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## Lifetim e W idths of Surface States on M agnetic Lanthanide M etals

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Low temperature scanning tunneling spectroscopy is used to study electronic structure and dynam ics of d-like surface states of trivalent lanthanide m etals from La to Lu. The magnetic exchange splitting of these states is found to scale with the 4f spin multiplied by an elective exchange-coupling constant that increases with 4f occupancy in an approximately linear way. The dynam ics of the surfaces states, as revealed by the lifetim elevidit, is dominated by electron-phonon scattering in the occupied region and by electron-magnon scattering in the unoccupied region, respectively.

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Electronic structure and dynamics of surface states have recently attracted substantial attention. For the noble metals, a profound understanding of binding energies and lifetim es of surface states has been achieved, m ainly due to im provem ents in the experim ental and theoretical techniques [1]. Here, for defect-free surfaces the lifetime of a surface state is predom inantly determ ined by electron-phonon (e-ph) and electron-electron (e-e) scattering rates, with the latter including both intraband and interband excitations [2]. On the other hand, much less is known on surface-state dynam ics in transition m etals, particularly in the lanthanides. A cross the series, the lanthanide m etals have sim ilar conduction-band structures but di erent 4f occupancies, n<sub>4f</sub>, and hence di erent 4fspin moments that interact with the (5d6s)-conduction electrons and the surface state by exchange interaction. Below specic tem peratures, all lanthanide metals with non-vanishing 4f m om ent exhibit long-range m agnetic order that causes an exchange splitting of the electronic states [3, 4, 5, 6]. For these magnetic transition metals, collective excitations of spin waves (magnons) provide additional decay channels for excited electronic states [7]. Electron-magnon (e-m) scattering processes, where an electron undergoes a spin- ip and a magnon is either created or annihilated, are di cult to distinguish from eph scattering processes since both are expected to exhibit. sim ilar tem perature dependences [8].

The electronic structure of surface states and their dynam ics can be studied by various techniques including photoem ission (PE), inverse photoem ission (IPE), twophoton-photoem ission (2PPE), and scanning tunneling spectroscopy (STS) [1]. While 2PPE is a time-resolved technique that can directly determ ine relaxation times, PE, IPE, and STS measure spectral lifetime widths of electronic states, i.e. inverse lifetim es.

In this Letter, we report on a systematic lowtemperature STS study of the  $5d_{z^2}$ -like surface states on the (0001) faces of trivalent lanthanide metals. The magnetic exchange splitting,  $e_x$ , of these laterally localized surface states is found to scale with the 4f spin moment multiplied by an elective exchange-coupling constant that increases with  $n_{4f}$  in an approximately linear way due to lanthanide contraction. Concerning the dynamics of the surface states, we nd much shorter lifetimes for the (unoccupied) m inority states as compared to the (occupied) m a jority states. While the lifetimes of the occupied states are mainly determined by e-ph scattering, the lifetimes of the unoccupied states are dominated by e-m scattering.

The experiments were performed in an ultrahigh vacuum (UHV) cham ber equipped with a low-tem perature scanning tunneling m icroscope (STM ) operated at 10 K [5]. The sam ples were prepared in-situ by electron-beam evaporation of the lanthanide m etals La  $(4f^0)$ , Nd  $(4f^3)$ , Gd (4f<sup>7</sup>), Tb (4f<sup>8</sup>), Dy (4f<sup>9</sup>), Ho (4f<sup>10</sup>), Er (4f<sup>11</sup>), Tm (4f<sup>12</sup>), or Lu (4f<sup>14</sup>), respectively, and deposition on a clean W (110) single crystal kept at room tem perature. Subsequently, the samples were annealed at tem peratures between 500 and 1000 K, resulting in sm ooth hop (0001) Im s (dhop in case of La and Nd) with atom ically at terraces, and local-thickness variations of only a few monolayers (ML) [5]. The average thickness of the deposited Im was monitored with a quartz microbalance. STS spectra were recorded with xed tip position and switched-o feedback control. The di erential conductivity, dI=dU , with I being the tunneling current and U the sample bias voltage, was measured as a function of U by modulating U and recording the induced modulation of I via lock-in technique. dI=dU is proportional to the density of states at the sam ple surface in good approximation. A modulation amplitude of 1 mV (rms) at a frequency of 360 H z w as used, with the tim e constant of the lock-in amplier set to 100 ms, at a sweep rate of

6 mV/s. To correct for binding energy shifts due to the nite time constant, the spectra were recorded in both directions, from lower to higher and from higher to lower sample bias. Since both the STM tip and the sample were cooled to 10 K, the energy resolution was 3 meV, corresponding to  $3.5 \text{ k}_{B} \text{ T}$ .

Fig. 1 shows tunneling spectra of the trivalent lanthanide m etals La, Nd, Gd, Tb, Dy, Ho, Er, Tm, and Lu. The d-like surface states are clearly resolved as pro-

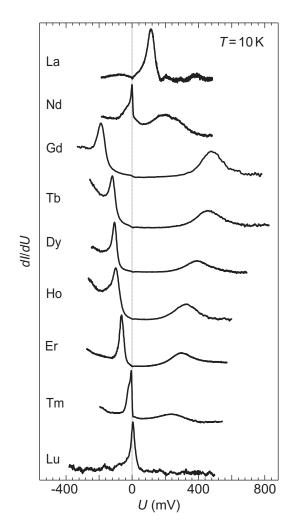


FIG.1: STS spectra of (0001)-surface states of the trivalent lanthanide m etals recorded at 10 K. The spectra are overview spectra. Better resolved spectra of each peak were used for data analysis, as described in detail in Ref. [5].

nounced peaks. For the lanthanides with non-vanishing 4f-spin moments, majority and minority exchange-split spin states appear below and above  $E_F$  (U = 0), respectively. For La and Lu, with  $n_{4f} = 0$  and  $n_{4f} = 14$ , respectively, the spectra exhibit a single peak. The strongly peaked density of surface states probed by STS is the consequence of a high degree of lateral localization, resulting in small dispersions of the surface-state bands with e ec-1 [5, 9]. For Nd and Tm, with tive masses m =m the majority surface states rather close to E  $_{\rm F}$  , and possibly also for Lu, additional sharp features directly at  $E_{\rm F}$ show up in the STS spectra that represent many-body resonances due to an interaction of the localized surface state with bulk conduction electrons; hence, these features can be described by Fano line shapes [10, 11].

D ue to the smalldispersions of the surface-state bands, the surface-state peaks in the tunneling spectra can be described by Lorentzian lines, with widths that are re-

lated to lifetimes by = h = .0 nly for narrow peaks, sm all deviations from a symmetric line shape due to dispersion are recognizable. Since the surface-state bands show a downward dispersion with a band maximum at (with the exception of Lu, for which an M -shaped dispersion had been calculated [11]), the trailing edges of the peaks in the STS spectra are generally steeper than the leading edges [5]. In order to account for this asymmetry, the peaks were tted with adequate superpositions of Lorentzian lines; a detailed description of the t procedure is given in Ref. [5]. Fit results for energies and linew idths in the present work refer to surface states at the band m axim um . In case of N d and Tm, the trailing edges of the surface-state peaks are superim posed on the m entioned resonances at E  $_{\rm F}$  , and the asymmetries of the peaks cannot be determ ined unam biquously. Therefore, single Lorentzian lines were tted to these peaks. The errors that result from a neglect of surface-state dispersion are less than 10 m eV for both the energies and the widths of the surface state [5].

Table I sum marizes the t results for the energies, E  $_{\rm H}$  and E  $_{\rm H}$ , and the widths, " and ", of the majority (") and m inority (#) surface states as obtained from numerous STS spectra for each lanthanidem etal. The exchange splittings,  $_{\rm ex}$  = E  $_{\rm H}$  E", are plotted in Fig.2(a) versus the 4f-spin quantum number S. A system atic deviation from a linear dependence is clearly observed. Furtherm ore, Nd exhibits a much smaller exchange splitting than E r, although both elements have the same 4f spin.

W e introduce an e ective exchange-coupling constant, J<sub>e</sub> =  $e_x = S$ , and plot the resulting  $J_e$  in Fig. 2(b) versus  $n_{4f}$ . In contrast to previous results [5, 12],  $J_e$ is not found to be constant for all lanthanide m etals but increases almost linearly with increasing  $n_{4f}$ . Another quantity that changes alm ost linearly with n<sub>4f</sub> as a consequence of lanthanide contraction is the lattice constant a [see open symbols in Fig. 2 (b)]. This suggests a relation between  $J_e$  and a of the form  $J_e$  / a, which is plausible, since the exchange interaction of the outer (5d6s) electronic states with the 4f core states will depend on the overlap of these states. A long this line, the sm aller exchange splitting observed for Nd as com pared to Tm can be understood, thing nicely into the general trend. It should be noted, however, that Nd has a rather complex spin structure at 10 K, with a vanishing net m om ent in the (0001) planes [13], w hereas the other heavy lanthanide m etals exhibit ferrom agnetic coupling of the 4f spins within the (0001) planes. This can also contribute to the sm aller exchange splitting observed for Nd (0001), since the surface state, although laterally highly localized, overlaps with neighboring atom s and, in this way, interacts with a reduced average 4f spin in the Nd case.

In the following, we discuss the lifetime widths of surface states. In Fig. 3, the values, listed in Table I, are plotted versus surface-state energies. As indicated by

		La		Nd		Gd		Τb		Dу		Ηο		Εr		Τm		Lu
				"	#	"	#	"	#	"	#	"	#	"	#	"	#	
	(meV)		49	70	120	33	134	22	184	19	170	19	125	30	146	29	190	5.0
Е	E <sub>F</sub> (	(m eV )	130	-18	187	-191	470	-111	474	-102	402	-90	347	-51	318	-19	240	2.0

TABLE I: Lifetim e width, , and energy, E  $E_F$ , of exchange-split (0001)-surface states on trivalent lanthanide m etals. The estim ated errors of the energies are 10 m eV, in case of Lu 1 m eV. The errors of the values are plotted in Fig. 3. M a jority and m inority states are denoted by " and #, respectively.

the two shaded areas, the lifetime widths of the majority states below  $E_F$  are considerably smaller than those of the minority states above  $E_F$ . In a previous study of G d and H o [5, 14], the enhanced lifetime widths were attributed to the larger absolute energies,  $E = E_F j$  of the unoccupied minority states, which, according to 3-dimensional Fermi-liquid theory, would result in increased e-e scattering rates:  $_{e e} = 2$  (E = E)<sup>2</sup> [15]. In this way, 2 values between 0.2 and 0.5 eV <sup>1</sup> were obtained, which are, however, up to an order of magnitude larger than the 2 values reported for otherm aterials [1],

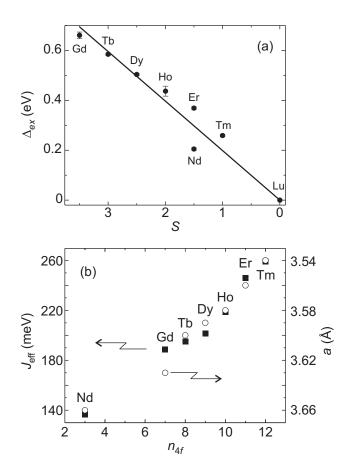


FIG.2: (a) Exchange splitting of (0001)-surface states,  $_{\rm ex}$ , at 10 K plotted versus 4f spin, S, of the studied lanthanide m etals. (b) E ective exchange-coupling constant,  $J_{\rm e}$ , and lattice constant, a, plotted versus 4f occupancy,  $n_{\rm 4f}$ , of various lanthanide m eals.

including Y b, a divalent lanthanide m etal with a  $4f^{14}$  con guration. In case of Y b, 2  $0.08 \text{ eV}^{-1}$  was recently determ ined from lifetim e widths of quantum -well states in thin Y b (0001) Im s [16]. A lthough we cannot completely rule out the possibility of large 2 values, the present results, based on a system atic study of trivalent lanthanide m etals, renders the previous conclusion questionable.

For surface states that lie in the center of a bandgap of the projected bandstructure, interband-transition rates are expected to be small since such transitions involve large m om entum transfers, k, and the C oulom b interaction scales with  $k^2$  [1]. Intraband transitions, on the other hand, may give signi cant, in som e cases even dom inant contributions to lifetime widths [17]. In the tunneling process, holes (U < 0) and electrons (U > 0) are predom inantly excited at , i.e. at the maximum of the surface-state band. W hile an excited electron in an unoccupied surface-state band can decay into low er-lying electronic states of the same band, there are no intraband decay channels available for a hole in an occupied surface-state band at . We therefore conclude that the dom inant contribution to lifetim e widths of the occupied surface states is e-ph scattering. For Lu, the surfacestate energy is smaller than the Debye energy so that even e-ph scattering is suppressed [5]. From tem peraturedependent m easurem ents of G d surface states, the zerotem perature contribution of e-ph scattering to the lifetime width was determined as  $_{e ph}$  = (22) 5) m eV [14]. Thus, e-ph scattering accounts for approximately 70% of the total lifetime width. Sim ilar values can be expected for the other lanthanide m etals.

For unoccupied surface states, intraband e-e scattering will be enhanced, explaining the increased lifetim e width of the unoccupied La-surface state by about 25 m eV as com pared to those of the occupied surface states.

So far, we have not taken into account e-m scattering of surface states due to exchange interaction with the 4f spins. For the occupied surface states, the sam e argument as given above for e-e scattering applies, i.e. the number of states into which an excited hole at or close to the surface-state band maximum can scatter is limited. Furthermore, due to the high degree of spin polarization of the surface state bands, intraband spin- ip scattering is suppressed, even for excited states below the surface-state band maximum. Previous studies of

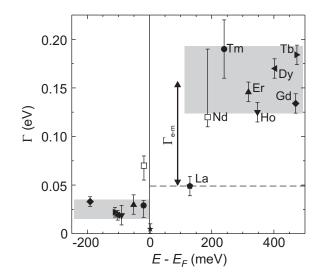


FIG.3: Lifetim e width, , versus surface-state energies, E  $E_{\rm F}$ , for the trivalent lanthanide m etals according to m easured values listed in Table I.

G d based on spin-resolved PE found an e-m-scattering contribution of 14 m eV to the lifetime width of the m a jority-spin state, but only if the state is more than 25 m eV { the highest m agnon energy { below the band m axim um [18, 19]. D ue to the sm all dispersions of the surface-state bands, most excited holes will be closer to the band m axim um so that the actual contribution of e-m scattering will be sm aller [5].

For unoccupied surface states on magnetic lanthanide m etals, both intraband and interband spin- ip transition rates will be enhanced. This explains the large lifetim e widths compared to those of the occupied surface states and also to that of the unoccupied surface state on nonmagnetic La metal. Again, intraband spin- ip transitions are only possible if the spin polarization of the surface-state band is less than 100% , e.g., due to spinorbit coupling [18, 19]. As for interband transitions, it is interesting to note that for Gd, and presum ably also for the otherm agnetic lanthanide m etals, the unoccupied m inority surface-state band lies outside the bandgap of the projected majority bandstructure, whereas the occupied m inority surface states are located within the total, spin-averaged bandgap [3]. Therefore, spin- ip transitions by magnon emission do not require large mom entum transfers, as spin-conserved transitions do, which could explain the enhanced scattering rates. If we make the assumption that the di erences in lifetime widths of the unoccupied surface states on magnetic lanthanide metals, on the one hand, and the lifetime width of the surface state on La(0001), on the other hand, is solely

due to e-m scattering, the e-m contribution amounts to (100 25) m eV; the error bar relects the scattering of

data points for di erent m etals (see Fig. 3).

F inally, we like to mention that the rather large lifetime width of the occupied surface state on N d is probably also due to e-m scattering. W hile the exchange-split surface states of the heavy lanthanide metals are nearly 100% spin polarized, the net polarization of N d surface states vanishes due to the antiferrom agnetic spin order within the (0001)-surface plane, allowing for enhanced spin-ip intraband scattering.

In sum m ary, the present work provides detailed inform ation on the electronic structure of surface states on lanthanide m etals, in particular on their energies, exchange splitting, and dynam ics. At this point, theoretical calculations are needed to corroborate the experim ental ndings and conclusions regarding the in uence of lanthanide contraction on exchange splitting as well as the contribution of e-ph, inter- and intraband e-e, and e-m scattering to the lifetim e widths of the surface states.

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